# NSN 5962-01-373-0569

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## **Body Length:**

Between 1.635 inches and 1.680 inches

## **Body Width:**

Between 0.565 inches and 0.605 inches

## **Body Height:**

Between 0.100 inches and 0.205 inches

## Maximum Power Dissipation Rating:

350.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Ultraviolet erasable and w/inhibit and w/disable and bidirectional

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

## Input Circuit Pattern:

20 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 7.0 volts power source

## **Capitance Rating Per Characteristic:**

12.00 input picofarads and 15.00 output picofarads

## Time Rating Per Chacteristic:

250.00 nanoseconds access

## Memory Device Type:

Eprom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

32 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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